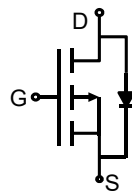
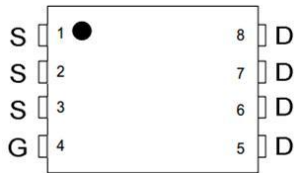
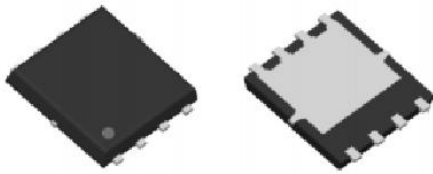


P-Channel Enhancement Mode Power MOSFET

General Description The G80P03D5 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge. It can be used in a wide variety of applications.		 Schematic diagram  pin assignment  DFN5*6	
General Features • V_{DS} -30V • I_D (at $V_{GS} = 10V$) -65A • $R_{DS(ON)}$ (at $V_{GS} = 10V$) < 6mΩ • $R_{DS(ON)}$ (at $V_{GS} = 4.5V$) < 8mΩ • 100% Avalanche Tested • RoHS Compliant			
Application • Power switch • DC/DC converters			
Device	Package	Marking	Packaging
G80P03D5	DFN5*6	G80P03	5000pcs/Reel

Absolute Maximum Ratings $T_C = 25^\circ C$, unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Continuous Drain Current	I_D	-65	A
Pulsed Drain Current (note1)	I_{DM}	-260	A
Gate-Source Voltage	V_{GS}	± 20	V
Power Dissipation	P_D	63	W
Single pulse avalanche energy (note2)	E_{AS}	196	mJ
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 To 150	$^\circ C$

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	R_{thJA}	50	$^\circ C/W$
Maximum Junction-to-Case	R_{thJC}	1.98	$^\circ C/W$

Specifications T _J = 25°C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static Parameters						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-30	--	--	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -30V, V _{GS} = 0V	--	--	-1	μA
Gate-Source Leakage	I _{GSS}	V _{GS} = ±20V	--	--	±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =- 250μA	-1	-1.5	-2.5	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} = -10V, I _D = -30A	--	5	6	mΩ
		V _{GS} = -4.5V, I _D = -30A	--	6.5	8	
Forward Transconductance	g _{FS}	V _{DS} = -5V,I _D = -30A	--	62	--	S
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{GS} = 0V, V _{DS} = -15V, f = 1.0MHz	--	5386	--	pF
Output Capacitance	C _{oss}		--	718	--	
Reverse Transfer Capacitance	C _{rss}		--	673	--	
Total Gate Charge	Q _g	V _{DD} = -15V, I _D = -30A, V _{GS} = -10V	--	95	--	nC
Gate-Source Charge	Q _{gs}		--	18	--	
Gate-Drain Charge	Q _{gd}		--	19	--	
Turn-on Delay Time	t _{d(on)}	V _{DD} = -15V, I _D = -30A, R _G = -2.5Ω	--	12	--	ns
Turn-on Rise Time	t _r		--	60	--	
Turn-off Delay Time	t _{d(off)}		--	80	--	
Turn-off Fall Time	t _f		--	65	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I _S	T _C = 25°C	--	--	-65	A
Body Diode Voltage	V _{SD}	T _J = 25°C, I _{SD} = -30A, V _{GS} = 0V	--	--	-1.2	V
Reverse Recovery Charge	Q _{rr}	I _F = -25A, V _{GS} = 0V di/dt=-100A/us	--	60	--	nC
Reverse Recovery Time	T _{rr}		--	52	--	ns

Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. EAS condition : $T_J = 25^{\circ}\text{C}$, $V_{DD} = -30V, V_{GS} = -10V, L = 0.5\text{mH}, R_G = 25\Omega$
3. Identical low side and high side switch with identical R_G

Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 1. Output Characteristics

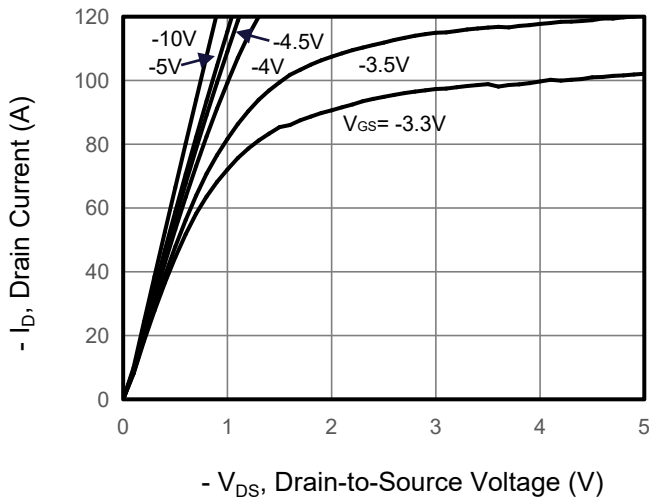


Figure 2. Transfer Characteristics

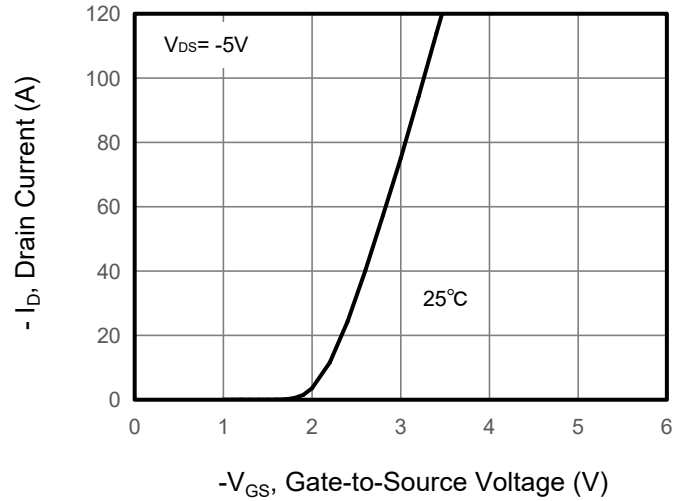


Figure 3. Drain Source On Resistance

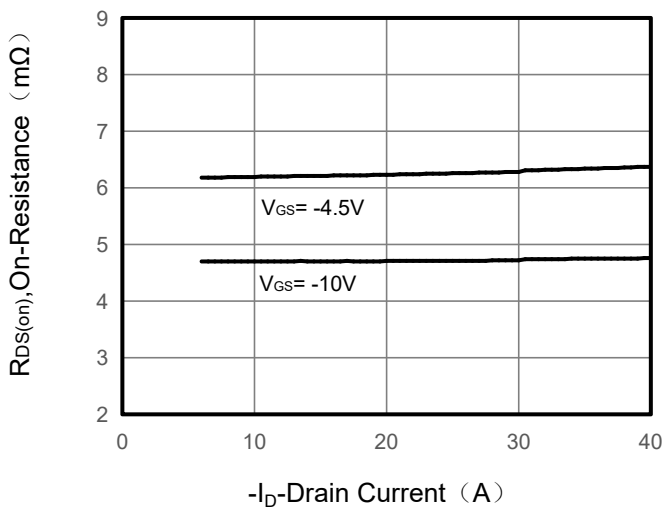


Figure 4. Gate Charge

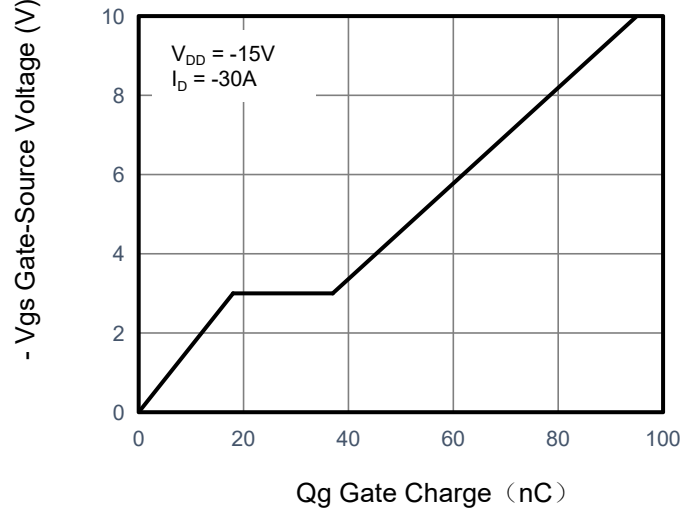


Figure 5. Capacitance

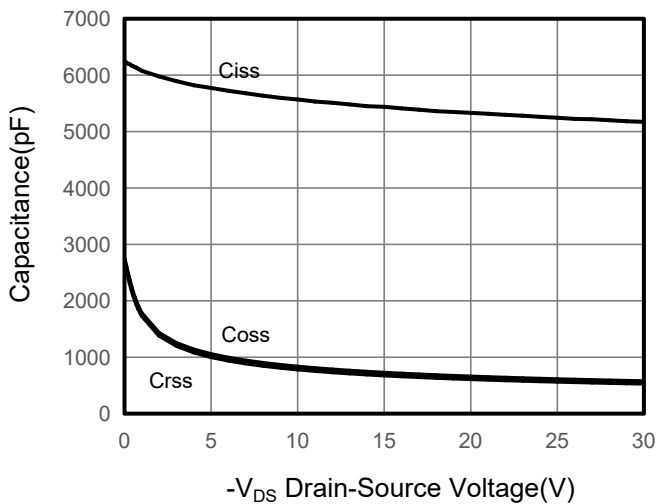
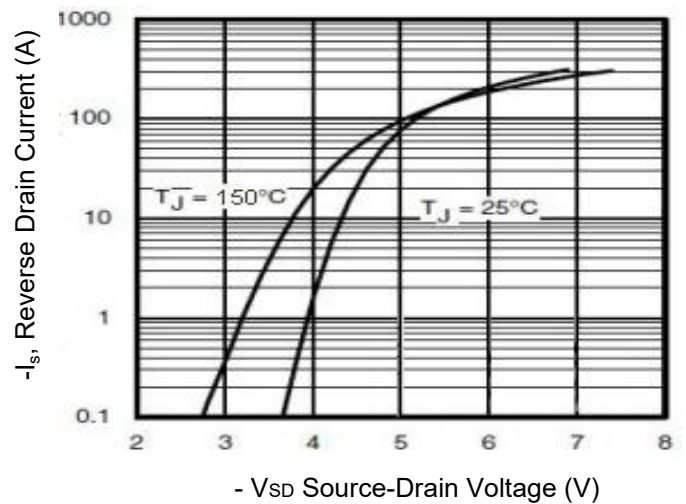


Figure 6. Source- Drain Diode Forward



Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 7. Drain-Source On-Resistance

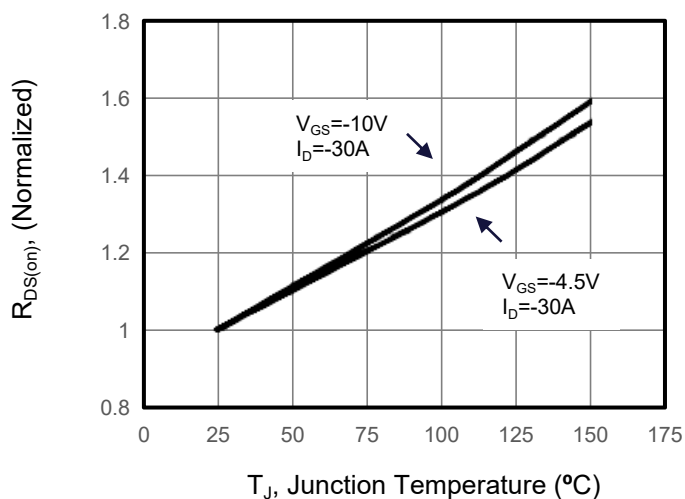


Figure 8. Safe Operation Area

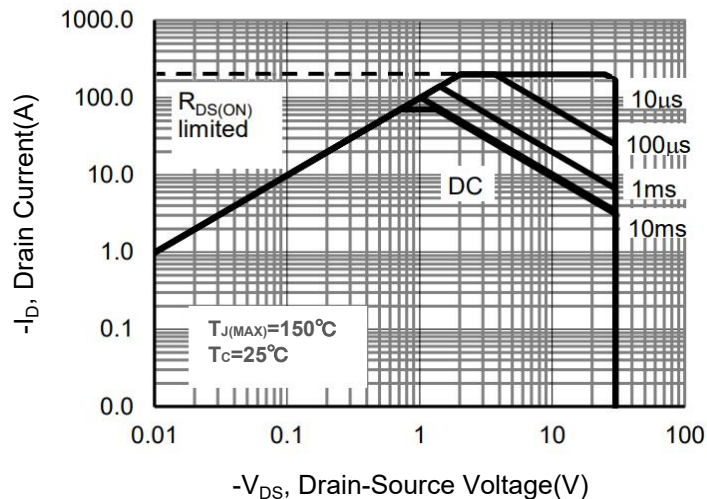
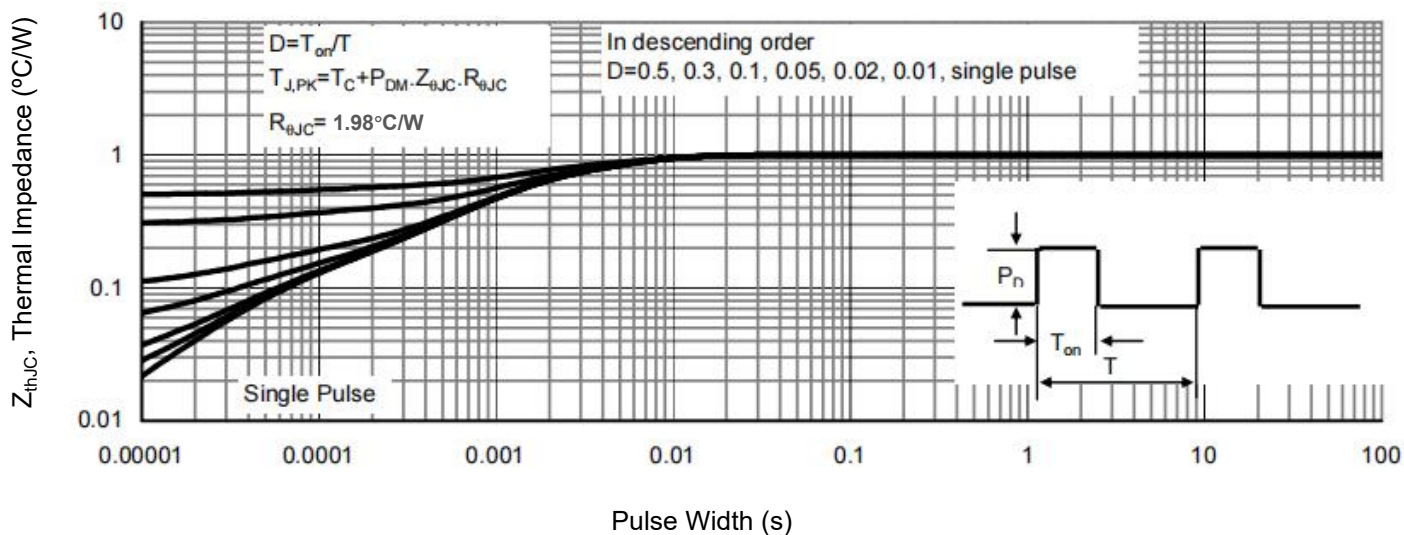
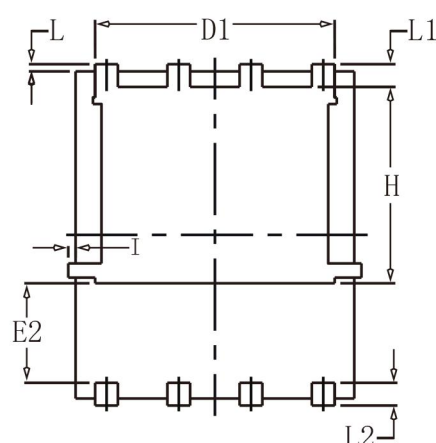
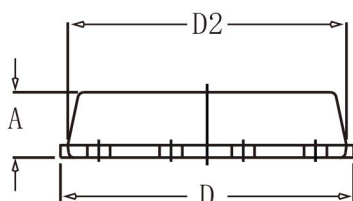
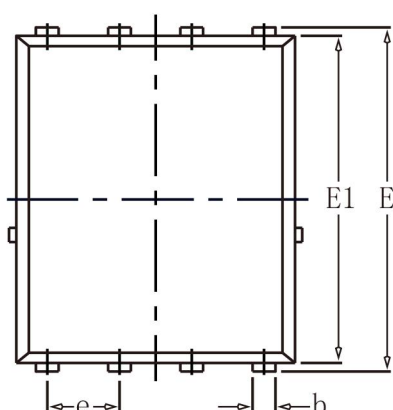


Figure 9. Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package information



SYMBOL	COMMON			
	MM		INCH	
	MIN	MAX	MIN	MAX
A	1.03	1.17	0.0406	0.0461
b	0.34	0.48	0.0134	0.0189
c	0.824	0.970	0.0324	0.0382
D	4.80	5.40	0.1890	0.2126
D1	4.11	4.31	0.1618	0.1697
D2	4.80	5.00	0.1890	0.1969
E	5.59	6.15	0.2343	0.2421
E1	5.65	5.85	0.2224	0.2303
E2	1.60	—	0.0630	—
e	1.27 BSC		0.05 BSC	
L	0.05	0.25	0.0020	0.0098
L1	0.38	0.50	0.0150	0.0197
L2	0.38	0.50	0.0150	0.0197
H	3.30	3.50	0.1299	0.1378
I	—	0.18	—	0.0070